Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic

Overall Length:

Between 0.515 inches and 0.565 inches

Overall Diameter:

Between 1.600 inches and 1.656 inches

End Application:

4931-00-951-5308 19200 fscm

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 repetitive peak off-state voltage and 600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage

Current Rating Per Characteristic:

275.00 amperes forward current, total rms horsepower metric

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector peak

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 2 insulated wire lead w/terminal lug

Shelf Life:

N/a

- Unit Of Measure:
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Demilitarization:

No

Fiig:

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